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Fairchild Semiconductor MMBT4354

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



EMICON	IDUCTOR®				
	MMI	BT4354			
This device switch requi Sourced fro	eral Purpose Amplifier is deisgned for use as general purpose amp iring collector currents to 500mA. m process 67. or characteristics.		3 1. Base 2. Em		2 2 7-23 rk: 79
	Maximum Ratings* T _a =25°C u				
Symbol	Parameter		Value		Units
CEO	Collector-Emitter Voltage Collector-Base Voltage		-60 -60		V
<u>сво</u>	Emitter-Base Voltage		-60 -5.0		V
EBO	Collector Current - Contin		-5.0		mA
<u>,</u> T _{STG}	Operating and Storage Junction Temp		- 55 ~ 150		°C
	limiting values above which the serviceability of any semi	-	00 100		<u> </u>
	I Characteristics T _a =25°C unless				
Symbol	Parameter		Min.	Max.	Units
Symbol Off Characte	Parameter	otherwise noted		Max.	Units
Symbol Off Characte (BR)CEO (BR)CBO	Parameter	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_E = 0$	Min.	Max.	
Symbol Off Characte (BR)CEO (BR)CBO (BR)EBO	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_E = 0$ $I_E = -10\muA, I_C = 0$	Min.		V V V
Symbol Off Characte (BR)CEO (BR)CBO (BR)EBO	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{E} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$	Min. -60 -60	-50	V V V nA
Symbol Off Character (BR)CEO (BR)CBO (BR)EBO CBO EBO	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_E = 0$ $I_E = -10\muA, I_C = 0$	Min. -60 -60		V V V
Symbol Off Character (BR)CEO (BR)CBO (BR)EBO CBO EBO On Character	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * Collector Cut-off Current	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{E} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$ $V_{EB} = -5.0V, V_{CE} = 0$	Min. -60 -60 -5.0	-50	V V V nA
Symbol Off Character (BR)CEO (BR)CBO (BR)EBO CBO EBO On Character	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{E} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$	Min. -60 -60	-50	V V V nA
Symbol Off Character (BR)CEO (BR)EBO CBO EBO On Character FE	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * Collector Cut-off Current	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_E = 0$ $I_E = -10\muA, I_C = 0$ $V_{CB} = -50V, I_E = 0$ $V_{EB} = -5.0V, V_{CE} = 0$ $V_{CE} = -5V, I_C = -0.1mA$ $V_{CE} = -5V, I_C = -1.0mA$ $V_{CE} = -5V, I_C = -10mA$ $V_{CE} = -5V, I_C = -10mA$	Min. -60 -60 -5.0 25 40 50 40	-50	V V V nA
Symbol Off Character (BR)CEO (BR)CBO CBO CBO On Character FE	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * DC Current Gain	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_E = 0$ $I_E = -10\muA, I_C = 0$ $V_{CB} = -50V, I_E = 0$ $V_{EB} = -5.0V, V_{CE} = 0$ $V_{EB} = -5.0V, V_{CE} = 0$ $V_{CE} = -5V, I_C = -0.1mA$ $V_{CE} = -5V, I_C = -1.0mA$ $V_{CE} = -5V, I_C = -1.0mA$	Min. -60 -60 -5.0 25 40 50 40	-50 -10 500 -0.15	V V V πΑ μΑ
Symbol Off Character /(BR)CEO /(BR)CBO (BR)EBO CBO BO On Character /FE /CE(sat) /BE(sat) /BE(on)	Parameter Parameter Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_C = 0$ $I_E = -10\muA, I_C = 0$ $V_{CB} = -50V, I_C = 0$ $V_{EB} = -5.0V, V_{CE} = 0$ $V_{CE} = -5V, I_C = -0.1mA$ $V_{CE} = -5V, I_C = -1.0mA$ $V_{CE} = -5V, I_C = -1.0mA$ $I_C = -150mA, I_B = -15mA$ $I_C = -150mA, I_B = -15mA$	Min. -60 -60 -5.0 25 40 50 40	-50 -10 500 -0.15 -0.50 -0.9	V V V ηΑ μΑ V V V V
Symbol Off Character (BR)CEO (BR)CEO (BR)CBO CBO CBO Dn Character FE 'CE(sat) 'BE(sat) 'BE(on) Gmall Signa	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage I Characteristics	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{C} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$ $V_{CB} = -50V, I_{C} = -0.1mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -10mA$ $V_{CE} = -5V, I_{C} = -10mA$ $V_{CE} = -5V, I_{C} = -10mA$ $I_{C} = -5V, I_{C} = -50mA$ $I_{C} = -500mA, I_{B} = -15mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{B} = -50mA$ $V_{CE} = -0.5V, I_{C} = -500mA$	Min. -60 -60 -5.0 -5	-50 -10 500 -0.15 -0.50 -0.9 -1.1 -1.1	V V V ηΑ μΑ V V V V V
Symbol Off Character (/gR)CEO (/gR)CEO (/gR)CBO CBO Sea On Character FE 'CE(sat) 'BE(sat) 'BE(on) Gmall Signa fe	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage I Characteristics Small Signal Current Gain	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{C} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$ $V_{CB} = -50V, I_{C} = -0.1mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -100mA$ $V_{CE} = -5V, I_{C} = -100mA$ $I_{C} = -500mA, I_{B} = -15mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{C} = -500mA$	Min. -60 -60 -5.0 25 40 50 40	-50 -10 500 -0.15 -0.50 -0.9 -1.1 -1.1 5.0	V V NA μA V V V V V V
Symbol Off Character /(BR)CEO /(BR)CEO /(BR)CBO CBO CBO CBO On Character /FE //CE(sat) //BE(sat) //BE(on) Gmall Signa Ife	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage I Characteristics Small Signal Current Gain Noise Figure	otherwise noted Test Condition $I_C = -1.0mA, I_B = 0$ $I_C = -10\muA, I_C = 0$ $I_E = -10\muA, I_C = 0$ $V_{CB} = -50V, I_E = 0$ $V_{CB} = -50V, I_C = -0.1mA$ $V_{CE} = -5V, I_C = -1.0mA$ $V_{CE} = -5V, I_C = -1.0mA$ $V_{CE} = -5V, I_C = -10mA$ $V_{CE} = -5V, I_C = -10mA$ $V_{CE} = -5V, I_C = -10mA$ $I_C = -50mA, I_B = -15mA$ $I_C = -150mA, I_B = -15mA$ $I_C = -500mA, I_B = -50mA$ $I_C = -500mA, I_B = -50mA$ $I_C = -0.5V, I_C = -500mA$	Min. -60 -60 -5.0 -5	-50 -10 500 -0.15 -0.50 -0.9 -1.1 -1.1	V V V ηΑ μΑ V V V V V
Symbol Off Character /(BR)CEO /(BR)CBO CBO EBO On Character On Character //FE //CE(sat) //BE(sat) //BE(on) Small Signa Iffe	Parameter Parameter Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage I Characteristics Small Signal Current Gain Noise Figure characteristics	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{C} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$ $V_{CB} = -50V, V_{CE} = 0$ $V_{CE} = -5V, I_{C} = -0.1mA$ $V_{CE} = -5V, I_{C} = -10mA$ $I_{C} = -50mA, I_{B} = -15mA$ $I_{C} = -500mA, I_{B} = -15mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{C} = -500mA$ $I_{C} = -500mA, I_{C} = -500mA$ $I_{C} = -10V, I_{C} = -10V, $	Min. -60 -60 -5.0 -5	-50 -10 500 -0.15 -0.50 -0.9 -1.1 -1.1 5.0	V V NA μA V V V V V V
Symbol Dff Character /(BR)CEO /(BR)CBO CBO EBO Dn Character DrFE /CE(sat) /BE(sat) /BE(sat) /BE(on) Small Signa Drfe	Parameter eristics Collector-Emitter Sustaining Voltage * Collector-Base Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current Emitter Cut-off Current eristics * DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage I Characteristics Small Signal Current Gain Noise Figure	otherwise noted Test Condition $I_{C} = -1.0mA, I_{B} = 0$ $I_{C} = -10\muA, I_{C} = 0$ $I_{E} = -10\muA, I_{C} = 0$ $V_{CB} = -50V, I_{E} = 0$ $V_{CB} = -50V, I_{C} = -0.1mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -1.0mA$ $V_{CE} = -5V, I_{C} = -10mA$ $V_{CE} = -5V, I_{C} = -10mA$ $I_{C} = -5V, I_{C} = -10mA$ $I_{C} = -50mA, I_{B} = -15mA$ $I_{C} = -500mA, I_{B} = -50mA$ $I_{C} = -500mA, I_{C} = -500mA$ $I_{C} = -0.5V, I_{C} = -10V, I_{C} = -10KHz, I_{C$	Min. -60 -60 -5.0 -5	-50 -10 500 -0.15 -0.50 -0.9 -1.1 -1.1 5.0	V V NA μA V V V V V V

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Rev. A, October 2003

MMBT4354



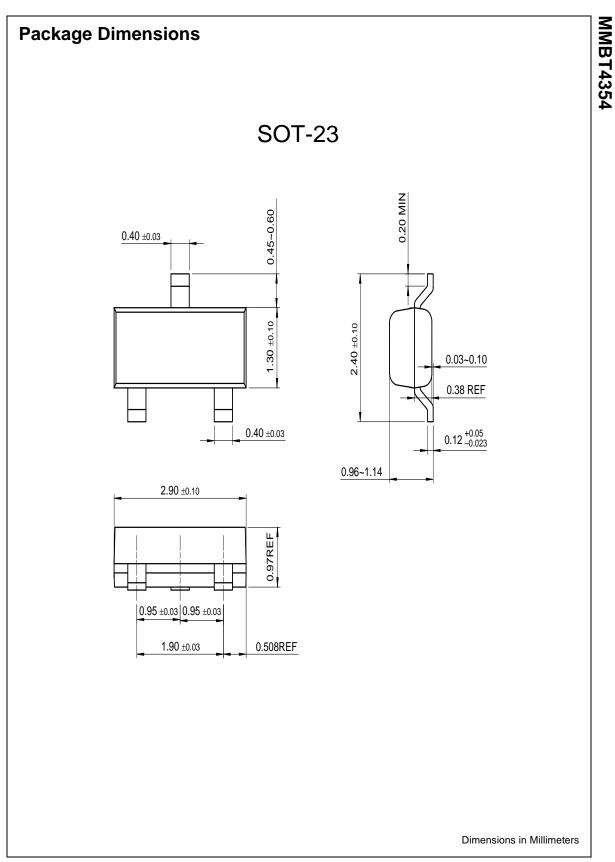
Symbol	Parameter	Max.	Units
D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
ς ^{θ]C}	Thermal Resistance, Junction to Case		°C/W
R _{θJC} R _{θJA}	Thermal Resistance, Junction to Ambient	357	°C/W

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Rev. A, October 2003





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Bottomless™	FASTr™	MicroFET™	QFET [®]	SyncFET™
CoolFET™	FRFET™	MicroPak™	QS™	TinyLogic®
CROSSVOLT™	GlobalOptoisolator™	MICROWIRE™	QT Optoelectronics [™]	TINYOPTO™
DOME™	GTO™	MSX™	Quiet Series™	TruTranslation™
EcoSPARK™	HiSeC™	MSXPro™	RapidConfigure™	UHC™
E ² CMOS [™]	I ² C [™]	OCX™	RapidConnect™	UltraFET [®]
EnSigna™	ImpliedDisconnect [™]	OCXPro™	SILENT SWITCHER [®]	VCX™
FACT™	ISOPLANAR™	OPTOLOGIC [®]	SMART START™	
Across the board.	Around the world. [™]	OPTOPLANAR™	SPM™	
The Power France	hise™	PACMAN™	Stealth™	
Programmable Ac	tive Droop™	POP™	SuperSOT™-3	

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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